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Submicron-diameter semiconductor pillar microcavities with very high quality factors

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Pillar microcavities are subject to two common fabrication artifacts: Bragg mirror corrugation and oxide deposit cladding. In this letter the authors investigate the impact of these features on the quality factor. A quasiperiodic variation of the quality factor as a function of the pillar diameter is experimentally observed and well described by theory. Moreover, observation of quality factors in excess of 1500, close to the theoretical limit, is reported for 600-nm-diameter GaAs micropillars bounded by AlGaAs/GaAs Bragg mirrors. © 2007 American Institute of Physics.

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FIG. 1. Micropillar geometry used in this work. (a) Cross-sectional TEM 002 dark-field image of a 570-nm-diameter micropillar (left and top-right figures: 002 dark-field images and bottom-right figure: TEM 111 dark-field image). (b) Schematic view of a micropillar showing the parameters used in the theoretical computations.
FIG. 2. (Color online) Numerical study of the impact of the oxide-adlayer cladding and of the DBR corrugation Δd on the micropillar Q. (a) Impact of the oxide adlayer. Q factors as a function of pillar diameter for oxide thickness εox=0 nm (solid blue curve) and 100 nm (dashed red curve). Calculations are performed with corrugation (Δd=80 nm). (b) Impact of the corrugation depth. Q factors as a function of pillar diameter for εox=0 nm and for several corrugation depths Δd=0 nm (solid blue curve), Δd=40 nm (dashed red curve), and Δd=80 nm (dashed-dotted green curve).

All pillars used in this study were fabricated from the same planar microcavity sample, grown by molecular beam epitaxy. The microcavities are composed of a 274 nm GaAs spacer, surrounded by N1=15 and N2=23 periods of alternating AL0.9Ga0.1As/GaAs layers, forming two distributed Bragg reflectors (DBRs). Every layer of pairs consists of a 68-nm-thick GaAs layer and a 80-nm-thick AL0.9Ga0.1As layer. The optically active medium is composed of three layers of InAs self-assembled quantum dots grown in the middle of the GaAs spacer with a density of approximately 4×10^{10} cm^{-2}. Arrays of different pillars with diameters ranging from 550 nm to 1.3 μm were fabricated through a combination of electron-beam lithography and SiCl4/O2 dry etching.1 A cross-sectional transmission electronic microscopy (TEM) image of a 570-nm-diameter micropillar is shown in Fig. 1(a). This type of image has been used for accurately measuring the different layer thicknesses. It shows that (1) the sidewalls are not straight but are corrugated with a 80 nm mean reduction of the Al0.9Ga0.1As layer diameter, compared with the GaAs layer diameter d, and that (2) they are clad with a SiO2 adlayer deposit whose thickness εox varies from 170 nm at the top of the pillars to 0 nm at the bottom and is around 100 nm in the vicinity of the cavity spacer. This adlayer is essential for the durability of the resonator since it prevents the formation of a friable aluminum oxide due to the spontaneous oxidation of the AL0.9Ga0.1As layers when in contact with air.

In order to assess the impact of the oxide cladding and of the corrugation on the quality factor Q of the cavity mode, we performed 3D fully vectorial calculations, using a modal expansion technique and assuming perfectly matched layers, while it uses analytical integration along the longitudinal pil-

odic variation of Q as a function of the micropillar diameter. The physical origin of these variations, namely, the coupling of the fundamental HE_{11} guided mode of the spacer to a propagative Bloch mode in the DBR mirrors whose strength depends on the overlap between these two modes, has been explained for Δd=εox=0 nm in a previous publication13 and will not be further discussed here. We simply note that, as expected, the same mechanism holds for corrugated and oxide-clad micropillars.

More interesting, in the present context, is the fact that the presence of the oxide adlayer does not result in a Q factor reduction but only in a displacement of the Q variation pattern to smaller diameters, with a slight enhancement of Q being even observed on Fig. 2(a) for εox=100 nm. The impact of the corrugation depth on the cavity mode Q factor is subtler. For moderate depths (Δd=40 nm) slightly smaller than that observed in the TEM picture of Fig. 1(a), the computed Q values are similar to those of the uncorrugated case (Δd=0 nm) and for micropillars of approximately 600 nm diameter the Q values exceed those of the planar cavity (Q_{ph}≈2800). By contrast, for larger corrugations (Δd =80 nm), the cavity Q’s rapidly decrease for d<700 nm. The physical origin of this trend is not obvious and deserves more theoretical studies, but we believe that it can be accounted for by the transverse mode-profile mismatch between the fundamental HE_{11} spacer guided mode and its associated evanescent DBR-Bloch modes;14 as the corrugation depth increases, the overlap between these two modes decreases and the net effect is a lowering of the Bragg mirror effective reflectivity, resulting in a decrease of the average Q factor, as evidenced by Fig. 2(b) for small d.’s.

In order to confirm these numerical results and to estimate the impact of additional extrinsic loss mechanisms not taken into account in the numerical model (such as sidewall roughness, local variation of corrugation depth and oxide thickness as well as a residual small cladding absorption), the Q’s of the processed pillars have been measured using the photoluminescence from the InAs quantum dots. The experimental data are obtained from microphotoluminescence measurements of single pillars in samples consisting of nine ideally identical pillars for 34 different diameters varying from 550 nm to 1.3 μm. The InAs quantum dots are excited nonresonantly by a continuous Ti:sapphire laser tuned to 810 nm and focused on the sample by a microscope objective (numerical aperture=0.4). The sample is kept at a temperature of 4 K and the luminescence, collected by the same objective, is sent to a 0.32 m spectrometer (~0.1 nm resolution) with a cooled silicon change coupled device. The quality factors of each pillar are deduced from the width of their photoluminescence spectra and the diameters of the pillars are deduced from the energy of the fundamental HE_{11} mode.

Figure 3 shows a comparison between the Q factors measured on the sample and those calculated for realistic pillar geometries, with εox=100 nm and Δd=80 nm. The black curve superimposed on the experimental data in Fig. 3(a) is obtained by averaging over the different cavity mode energies in order to account for pillar-diameter dispersion due to technological inaccuracies. For large diameters, d > 1 μm, diameter fluctuations do not strongly impact the cavity mode energies so that for each series of nine ideally identical pillars, their cavity mode energies are very close. In this case, we can extract a mean Q value for each series by simply averaging the measured Q’s over the nine pillars.
the series. However, for $d < 1 \mu m$, the cavity mode energies rapidly vary with $d$ so that the same mode energy can be measured for pillars belonging to different diameter series. For the sake of clarity, we have removed these fluctuations by averaging the measured $Q$’s over a $N$-nearest-neighbor window. The black curve in Fig. 3(a) is obtained for $N = 15$, but actually does not depend on $N$. Virtually identical results showing the same minima are obtained for $N = 10$ and 20.

The discrepancies between the theoretical and experimental results can be easily understood: the fact that experimental $Q$’s are systematically smaller than the theoretical values can be attributed to the optical quality of the cladding, in which there is probably a slight absorption. Then, the discrepancies observed for pillars with $d < 700 \text{ nm}$ and, in particular, the strong peak predicted by the model at $d = 600 \text{ nm}$, which is not observed experimentally, are probably due to the fact that for small diameters, the relative size of the corrugation and of the oxide thickness becomes critical, and the local variations of these parameters are no longer negligible. Clearly, at small diameters, a more complete model would be necessary to take into account the local variations, as observed on the TEM images. Nevertheless, a comparison of the experimental and theoretical figures shows good qualitative agreement for pillars with $d > 700 \text{ nm}$. In particular, the variation of the measured $Q$’s as a function of $d$ exhibits oscillations, with minima at 690, 780, and 920 nm in agreement with the theoretical model and for $d = 730 \text{ nm}$ the experimental $Q$ values reach and almost rise above the $Q$ of the planar cavity.

These observations strongly support the theory in Ref. 13 and the computational model used in this work. It should also be noted that for the thinnest pillars measured ($d = 570 \text{ nm}$), the $Q$ factor reaches a value of 1500, only slightly smaller than the theoretical value of 1800, underscoring the good quality of the fabrication process. Moreover, these cavities with diameters in the range $d = 500–600 \text{ nm}$ possess a mode volume of the order of $2(\lambda/n)^3$ and so potentially offer Purcell factors as high as 35 with very efficient light extraction.

In conclusion, by studying theoretically and experimentally the quality factor of micropillars with submicron diameters, displaying fabrication-induced corrugated mirrors, and oxide cladding, we have developed an accurate model that accounts for the diameter-dependent variations of $Q$, for micropillars with $d > 700 \text{ nm}$. We expect that this analysis will be helpful for further optimizations of the design and fabrication of micropillars. In particular, by tailoring the corrugation and the oxide thickness, it may be possible to fabricate micropillars with $Q$’s larger than those reported here and also larger than the planar microcavity, provided that a given pillar diameter is targeted. Combined with a very efficient light extraction, such high-$Q$ and small-$V$ resonators are promising candidates for the implementation of quantum electrodynamics effects in the solid state.

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